

1 N 5317	Fch,Msc,Sem	Si-Di	SS, 80V, 0,125A, <4ns	31a	DO-34	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5318	Fch,Msc,Sem	Si-Di	SS, 75V, 0,125A, <4ns	31a	DO-34	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5319	Fch,Msc,Sem	Si-Di	SS, 40V, 0,1A, <4ns	31a	DO-34	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
1 N 5320	USA	Si-Di	S, 120V, 1A, <250ns	31a	SOD-17	BY 201/2, BY 296...299, BYX 58/200, ++
1 N 5321	Sol	Si-Di	Schottky, 30V, Uf<1V(50mA)	31a	DO-35	-
1 N 5322	Sol	Si-Di	Schottky, 30V, Uf<1V(35mA)	31a	DO-35	-
1 N 5323	Sol	Si-Di	Schottky, 20V, Uf<1V(35mA)	31a	DO-35	-
1 N 5324	USA	Si-Di	kV-Rr, 15k, 0,01A	31a	(38x13mmØ)	HS 10
1 N 5326	Trw	Si-Di	Rr, 200V, 12A	31a	(5x13mmØ)	-
1 N 5329	Sem	Si-Di	kV-Rr, 6kV, 0,135A	31a	(16x10mmØ)	BYX 90, 1N5183
1 N 5330	Sem	Si-Di	Rr, 1500V, 0,54A	31a	(13x5mmØ)	BY 269, DM 513, EM 516, GP 10W, ++
1 N 5331	USA,Gen	Si-Di	P Rr, 1200V, 12A(Tc=150°), Uf<0,55V(12A, 150°)	32a	DO-4	BYW 88/1200, 1N4511
1 N 5332	USA,Gen	Si-Di	P Rr, 1200V, 35A(Tc=140°), Uf<1,7V(35A, 140°)	32a	DO-5	1N4530
1 N 5333	USA,Mot,Sie	Z-Di	3,3V, 20%, 5W	31a	=DO-27	BZV 40/..., BZV 48/...
1 N 5334		Z-Di	=1N5333: 3,6V	31a	=DO-27	
1 N 5335		Z-Di	=1N5333: 3,9V	31a	=DO-27	
1 N 5336		Z-Di	=1N5333: 4,3V	31a	=DO-27	
1 N 5337		Z-Di	=1N5333: 4,7V	31a	=DO-27	
1 N 5338		Z-Di	=1N5333: 5,1V	31a	=DO-27	
1 N 5339		Z-Di	=1N5333: 5,6V	31a	=DO-27	
1 N 5340		Z-Di	=1N5333: 6V	31a	=DO-27	
1 N 5341		Z-Di	=1N5333: 6,2V	31a	=DO-27	
1 N 5342		Z-Di	=1N5333: 6,8V	31a	=DO-27	
1 N 5343		Z-Di	=1N5333: 7,5V	31a	=DO-27	
1 N 5344		Z-Di	=1N5333: 8,2V	31a	=DO-27	
1 N 5345		Z-Di	=1N5333: 8,7V	31a	=DO-27	
1 N 5346		Z-Di	=1N5333: 9,1V	31a	=DO-27	
1 N 5347		Z-Di	=1N5333: 10V	31a	=DO-27	
1 N 5348		Z-Di	=1N5333: 11V	31a	=DO-27	
1 N 5349		Z-Di	=1N5333: 12V	31a	=DO-27	
1 N 5350		Z-Di	=1N5333: 13V	31a	=DO-27	
1 N 5351		Z-Di	=1N5333: 14V	31a	=DO-27	
1 N 5352		Z-Di	=1N5333: 15V	31a	=DO-27	
1 N 5353		Z-Di	=1N5333: 16V	31a	=DO-27	
1 N 5354		Z-Di	=1N5333: 17V	31a	=DO-27	
1 N 5355		Z-Di	=1N5333: 18V	31a	=DO-27	
1 N 5356		Z-Di	=1N5333: 19V	31a	=DO-27	
1 N 5357		Z-Di	=1N5333: 20V	31a	=DO-27	
1 N 5358		Z-Di	=1N5333: 22V	31a	=DO-27	
1 N 5359		Z-Di	=1N5333: 24V	31a	=DO-27	
1 N 5360		Z-Di	=1N5333: 25V	31a	=DO-29	
1 N 5361		Z-Di	=1N5333: 27V	31a	=DO-27	
1 N 5362		Z-Di	=1N5333: 28V	31a	=DO-27	
1 N 5363		Z-Di	=1N5333: 30V	31a	=DO-27	
1 N 5364		Z-Di	=1N5333: 33V	31a	=DO-27	
1 N 5365		Z-Di	=1N5333: 36V	31a	=DO-27	
1 N 5366		Z-Di	=1N5333: 39V	31a	=DO-27	
1 N 5367		Z-Di	=1N5333: 43V	31a	=DO-27	
1 N 5368		Z-Di	=1N5333: 47V	31a	=DO-27	
1 N 5369		Z-Di	=1N5333: 51V	31a	=DO-27	
1 N 5370		Z-Di	=1N5333: 56V	31a	=DO-27	
1 N 5371		Z-Di	=1N5333: 60V	31a	=DO-27	
1 N 5372		Z-Di	=1N5333: 62V	31a	=DO-27	
1 N 5373		Z-Di	=1N5333: 68V	31a	=DO-27	
1 N 5374		Z-Di	=1N5333: 75V	31a	=DO-27	
1 N 5375		Z-Di	=1N5333: 82V	31a	=DO-27	
1 N 5376		Z-Di	=1N5333: 87V	31a	=DO-27	
1 N 5377		Z-Di	=1N5333: 91V	31a	=DO-27	
1 N 5378		Z-Di	=1N5333: 100V	31a	=DO-27	
1 N 5379		Z-Di	=1N5333: 110V	31a	=DO-27	
1 N 5380		Z-Di	=1N5333: 120V	31a	=DO-27	
1 N 5381		Z-Di	=1N5333: 130V	31a	=DO-27	
1 N 5382		Z-Di	=1N5333: 140V	31a	=DO-27	
1 N 5383		Z-Di	=1N5333: 150V	31a	=DO-27	
1 N 5384		Z-Di	=1N5333: 160V	31a	=DO-27	
1 N 5385		Z-Di	=1N5333: 170V	31a	=DO-27	
1 N 5386		Z-Di	=1N5333: 180V	31a	=DO-27	
1 N 5387		Z-Di	=1N5333: 190V	31a	=DO-27	
1 N 5388		Z-Di	=1N5333: 200V	31a	=DO-27	
1 N 5333A...5388A		Z-Di	=1N5333...5388: 10%	31a	=DO-27	
1 N 5333B...5388B		Z-Di	=1N5333...5388: 5%	31a	=DO-27	
1 N 5389	Edi	Si-Di	kV-Rr, 40kV, Uf<80V(0,1A), 200ns	31a	-	-
1 N 5390	Fch,Tho	Si-Di	Schottky, 5V, Uf<0,55V(10mA)	31a	DO-7	-
1 N 5391(A)	USA,Mot,Tho	Si-Di	Rr, 50V, 1,5A, Uf<1,4V(1,5A, 70°), 2µs	31a	DO-15	BY 251...255, BY 226...227, BYW 52...56, ++
1 N 5392(A)		Si-Di	=1N5391: 100V	31a	DO-15	BY 251...255, BY 226...227, BYW 52...56, ++
1 N 5393(A)		Si-Di	=1N5391: 200V	31a	DO-15	BY 251...255, BY 226...227, BYW 52...56, ++
1 N 5394(A)		Si-Di	=1N5391: 300V	31a	DO-15	BY 252...255, BY 226...227, BYW 53...56, ++
1 N 5395(A)		Si-Di	=1N5391: 400V	31a	DO-15	BY 252...255, BY 226...227, BYW 53...56, ++
1 N 5396(A)		Si-Di	=1N5391: 500V	31a	DO-15	BY 253...255, BY 226...227, BYW 54...56, ++
1 N 5397(A)		Si-Di	=1N5391: 600V	31a	DO-15	BY 253...255, BY 226...227, BYW 54...56, ++
1 N 5398(A)		Si-Di	=1N5391: 800V	31a	DO-15	BY 254...255, BY 227, BYW 55...56, ++
1 N 5399(A)		Si-Di	=1N5391: 1000V	31a	DO-15	BY 255, BY 227, BYW 56, GP 15M, ++
1 N 5400(K)	USA,Mot,Tho	Si-Di	Rr, 50V, 3A, Uf<1,2V(9,4A), 5µs, K: DO-15	31a	DO-27A	BY 255
1 N 5401(K)		Si-Di	=1N5400: 100V	31a	DO-27A	BY 255
1 N 5402(K)		Si-Di	=1N5400: 200V	31a	DO-27A	BY 255
1 N 5403(K)		Si-Di	=1N5400: 300V	31a	DO-27A	BY 255
1 N 5404(K)		Si-Di	=1N5400: 400V	31a	DO-27A	BY 255
1 N 5405(K)		Si-Di	=1N5400: 500V	31a	DO-27A	BY 255
1 N 5406(K)		Si-Di	=1N5400: 600V	31a	DO-27A	BY 255
1 N 5407(K)		Si-Di	=1N5400: 800V	31a	DO-27A	BY 255
1 N 5408(K)		Si-Di	=1N5400: 1000V	31a	DO-27A	BY 255
1 N 5409	USA	Si-Di	P Rr, 300V, 40A(Tc=100°), Uf<1,2V(40A, 100°)	32a	DO-5	BYX 97/300
1 N 5410	USA	Si-Di	P Rr, 300V, 12A(Tc=100°), Uf<1V(12A, 100°)	32a	DO-4	BYW 88/300, BYX 78...81, 1N4507...11, ++